

# 45 V, 100 mA PNP general-purpose transistor Rev. 01 — 19 March 2007

**Product data sheet** 

#### **Product profile** 1.

### 1.1 General description

PNP general-purpose transistor in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

NPN complement: 2PD601ART.

### 1.2 Features

- General-purpose transistor
- Small SMD plastic package

### 1.3 Applications

General-purpose switching and amplification

### 1.4 Quick reference data

#### Table 1. **Quick reference data** Symbol Parameter Conditions Min Тур Max Unit collector-emitter voltage open base -45 V V<sub>CEO</sub> -- $I_C$ collector current --100 mΑ -DC current gain $V_{CE} = -10 V;$ 210 340 h<sub>FE</sub> - $I_{\rm C} = -2 \, \rm mA$

#### **Pinning information** 2.

Pin	Description	Simplified outline	Symbol
1	base	—	
2	emitter		3
3	collector		
			sym013



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### 3. Ordering information

Table 3. Order	ring informa	tion	
Type number	Package		
	Name	Description	Version
2PB709ART	-	plastic surface-mounted package; 3 leads	SOT23

### 4. Marking

Table 4. Marking codes	
Type number	Marking code <sup>[1]</sup>
2PB709ART	C5*

- [1] \* = -: made in Hong Kong
  - \* = p: made in Hong Kong
  - \* = t: made in Malaysia
  - \* = W: made in China

### 5. Limiting values

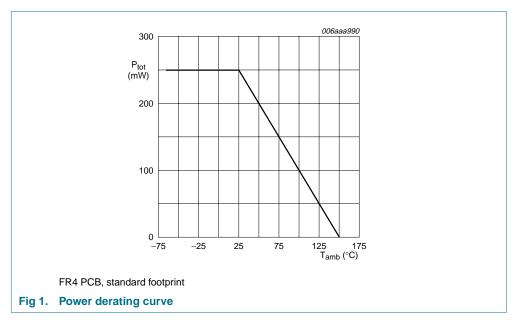
#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

		0, (	,		
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	-	-45	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-45	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	-6	V
I <sub>C</sub>	collector current		-	-100	mA
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-200	mA
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	<u>[1]</u> -	250	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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### 6. Thermal characteristics

Table 6.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	<u>[1]</u> -	-	500	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		-	-	140	K/W

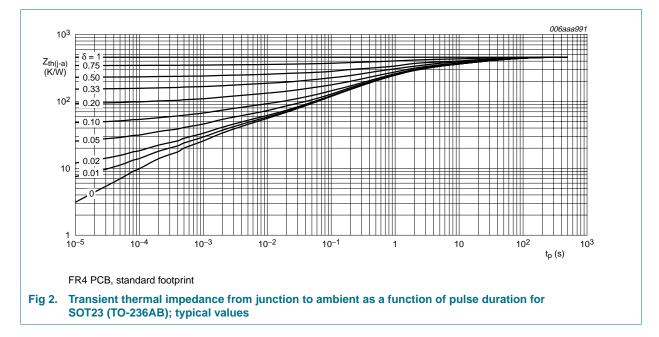
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

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### 7. Characteristics

#### Table 7. Characteristics

 $T_{amb} = 25 \,^{\circ}C$  unless otherwise specified.

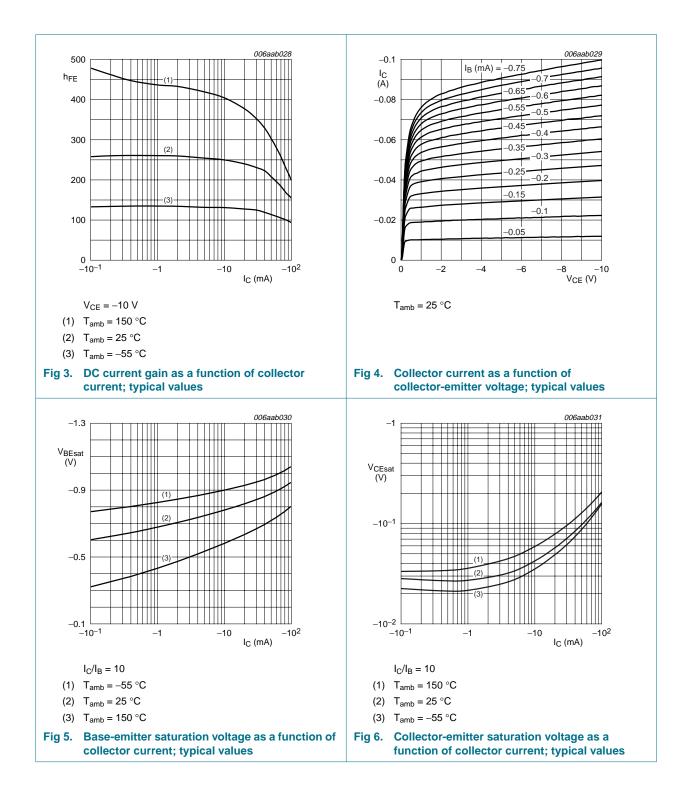
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	$V_{CB} = -45 \text{ V}; I_E = 0 \text{ A}$		-	-	-10	nA
	current	$\label{eq:VCB} \begin{array}{l} V_{CB} = -45 \ \text{V}; \ \text{I}_{E} = 0 \ \text{A}; \\ T_{j} = 150 \ ^{\circ}\text{C} \end{array}$		-	-	-5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$		-	-	-10	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = -10 \text{ V};$ $I_C = -2 \text{ mA}$		210	-	340	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{\rm C} = -100 \text{ mA};$ $I_{\rm B} = -10 \text{ mA}$	<u>[1]</u>	-	-	-500	mV
f <sub>T</sub>	transition frequency	$V_{CE} = -10 V;$ $I_{C} = -1 mA;$ f = 100 MHz		70	-	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = -10 \text{ V};$ $I_E = i_e = 0 \text{ A};$ f = 1  MHz		-	-	5	pF

[1] Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ .

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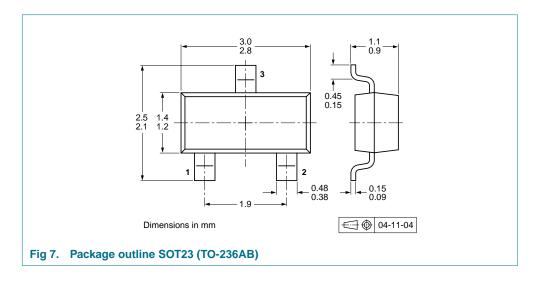
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### 8. Package outline



### 9. Packing information

#### Table 8. Packing methods

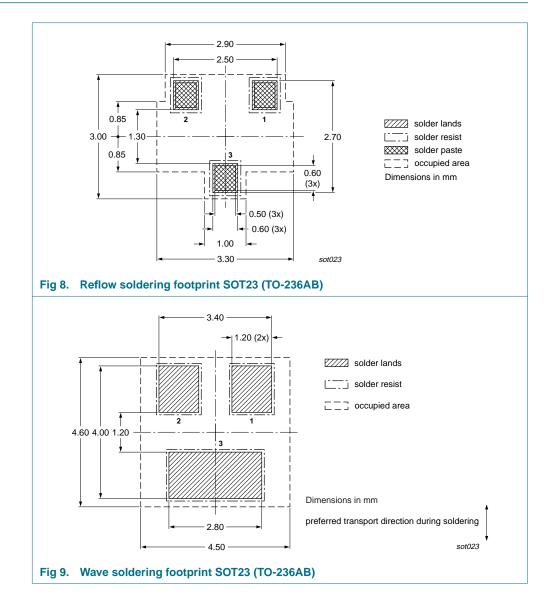
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description Packing quant		uantity
			3000	10000
2PB709ART	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235

[1] For further information and the availability of packing methods, see <u>Section 13</u>.

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### 10. Soldering



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### 11. Revision history

Table 9. Revision hist	Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes	
2PB709ART_1	20070319	Product data sheet	-	-	

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### 12. Legal information

### **12.1 Data sheet status**

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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